

# Thyristor/Diode (Super MAGN-A-PAK Power Modules), 570 A



Super MAGN-A-PAK

PRIMARY CHARACTERISTICS				
I <sub>T(AV)</sub>	570 A			
Туре	Modules - thyristor/diode			
Package	Super MAGN-A-PAK			

#### **FEATURES**

- · High current capability
- High surge capability
- Industrial standard package
- 3000 V<sub>RMS</sub> isolating voltage with non-toxic substrate
- · Designed and qualified for industrial level
- UL approved file E78996
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

### **TYPICAL APPLICATIONS**

- Motor starters
- DC motor controls AC motor controls
- Uninterruptible power supplies

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I <sub>T(AV)</sub> , I <sub>F(AV)</sub>	T <sub>C</sub> = 74 °C	570			
I <sub>T(RMS)</sub>	T <sub>C</sub> = 74 °C	895			
I <sub>TSM</sub>	50 Hz	17 800	A		
	60 Hz	18 700			
l²t	50 Hz	1591	kA <sup>2</sup> s		
1-1	60 Hz	1452	— KA <sup>z</sup> s		
I <sup>2</sup> √t		15 910	kA <sup>2√</sup> s		
V <sub>RRM</sub>	Range	1800	V		
T <sub>Stg</sub>	Range	-40 to +135	°C		
TJ	Range	-40 to +135			

#### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS						
TYPE NUMBER	VOLTAGE CODE	V <sub>RRM</sub> /V <sub>DRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	$\begin{aligned} I_{RRM}/I_{DRM} & \text{MAXIMUM} \\ \text{AT T}_{J} &= \text{T}_{J} & \text{MAXIMUM} \\ & \text{mA} \end{aligned}$		
VS-VSKH570-18PbF	18	1800	1900	120		



ON-STATE CONDUCTION						
PARAMETER	SYMBOL		TEST CONDI	TIONS	VALUES	UNITS
Maximum average on-state current	I <sub>T(AV)</sub>	190° conductio	180° conduction, half sine wave		570	Α
at case temperature	I <sub>F(AV)</sub>	180 Conductio	n, nan sine wave		74	°C
Maximum RMS on-state current	I <sub>T(RMS)</sub>	180° conductio	n, half sine wave	at T <sub>C</sub> = 74 °C	895	Α
		t = 10 ms	No voltage		17.8	
Maximum peak, one-cycle,	I <sub>TSM.</sub>	t = 8.3 ms	reapplied		18.7	kA
non-repetitive on-state surge current	I <sub>FSM</sub>	t = 10 ms	100 % V <sub>RBM</sub>		15.0	KA
		t = 8.3 ms	reapplied	Sinusoidal	15.7	1
		t = 10 ms	No voltage	half wave, initial T <sub>J</sub> = T <sub>J</sub> maximum	1591	- kA <sup>2</sup> s
Marriago na 124 faméraia a	l <sup>2</sup> t	t = 8.3 ms	reapplied		1452	
Maximum I <sup>2</sup> t for fusing	1-1	t = 10 ms	100 % V <sub>RBM</sub>		1125	
		t = 8.3 ms	reapplied		1027	
Maximum I²√t for fusing	I²√t	t = 0.1 ms to 10 ms, no voltage reapplied		15 910	kA²√s	
Low level value or threshold voltage	V <sub>T(TO)1</sub>	(16.7 % x $\pi$ x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$ ), $T_J = T_J$ maximum		0.864	V	
High level value of threshold voltage	V <sub>T(TO)2</sub>	$(I > \pi \times I_{T(AV)}), T_{x}$	<sub>J</sub> = T <sub>J</sub> maximum		0.97	v
Low level value on-state slope resista	nce r <sub>t1</sub>	$(16.7 \% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$		0.411	0	
High level value on-state slope resista	nce r <sub>t2</sub>	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$		0.362	mΩ	
SC SC	R V <sub>TM</sub>	$I_{pk} = 1500 \text{ A}, T_{J} = 25 \text{ °C}, t_{p} = 10 \text{ ms sine pulse}$		1.50	W	
Maximum on-state voltage drop Dic	ode V <sub>FM</sub>			1.50	V	
Maximum holding current	I <sub>H</sub>	T 05 %0	ala accessio 40 V		500	0
Maximum latching current	ΙL	T <sub>J</sub> = 25 °C, anode supply 12 V resistive load		1000	mA	

SWITCHING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum rate of rise of turned-on current	dl/dt	$T_J = T_J$ maximum, $I_{TM} = 400$ A, $V_{DRM}$ applied	1000	A/µs	
Typical delay time	t <sub>d</sub>	Gate current 1 A, $dI_g/dt = 1 A/\mu s$ $V_d = 0.67 \% V_{DRM}$ , $T_J = 25 °C$	2.0		
Typical turn-off time	t <sub>q</sub>	$I_{TM}$ = 750 A; $T_J$ = $T_J$ maximum, dl/dt = - 60 A/μs, $V_R$ = 50 V, dV/dt = 20 V/μs, gate 0 V 100 $\Omega$	200	μs	

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum, linear to $V_D = 80 \% V_{DRM}$	1000	V/µs
RMS insulation voltage	V <sub>INS</sub>	t = 1 s	3000	V
Maximum peak reverse and off-state leakage current	I <sub>RRM</sub> , I <sub>DRM</sub>	$T_J = T_J$ maximum, rated $V_{DRM}/V_{RRM}$ applied	120	mA



TRIGGERING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum peak gate power	$P_{GM}$	$T_J = T_J \text{ maximum}, t_p \le 5 \text{ ms}$	10	W
Maximum peak average gate power	P <sub>G(AV)</sub>	$T_J = T_J$ maximum, $f = 50$ Hz, $d\% = 50$	2.0	VV
Maximum peak positive gate current	+I <sub>GM</sub>		3.0	Α
Maximum peak positive gate voltage	+V <sub>GM</sub>	$T_J = T_J$ maximum, $t_p \le 5$ ms	20	V
Maximum peak negative gate voltage	-V <sub>GM</sub>		5.0	
Maximum DC gate current required to trigger	I <sub>GT</sub>	T 05 °C V 10 V	200	mA
DC gate voltage required to trigger	V <sub>GT</sub>	T <sub>J</sub> = 25 °C, V <sub>ak</sub> 12 V	3.0	V
DC gate current not to trigger	I <sub>GD</sub>	$T_J = T_J$ maximum	10	mA
DC gate voltage not to trigger	$V_{GD}$		0.25	V

THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction operating temperature range	TJ		-40 to +135	°C
Maximum storage temperature range	T <sub>Stg</sub>		-40 to +135	
Maximum thermal resistance, junction to case per junction	R <sub>thJC</sub>	R <sub>thJC</sub> DC operation		14004
Maximum thermal resistance, case to heatsink	R <sub>thC-hs</sub>		0.02 K/W	
Mounting Super MAGN-A-PAK to heats	ink	A mounting compound is recommended and the torque should be rechecked after a period	6 to 8	Nm
torque busbar to super MAGN-A-P	AK	of 3 hours to allow for the spread of the compound	12 to 15	INIII
Approximate weight			1500	g
Case style		See dimensions (link at the end of datasheet)	Super MAGN-	-A-PAK

△R <sub>thJC</sub> CONDUCTIO	N			
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS
180°	0.009	0.006		
120°	0.011	0.011		
90°	0.014	0.015	$T_J = T_J$ maximum	K/W
60°	0.021	0.022		
30°	0.037	0.038		

#### Note

• Table shows the increment of thermal resistance R<sub>thJC</sub> when devices operate at different conduction angles than DC

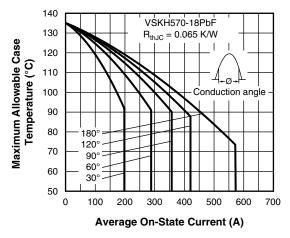


Fig. 1 - Current Ratings Characteristics

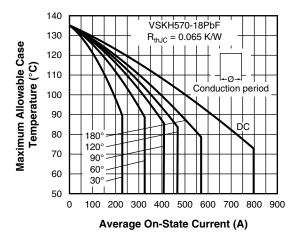


Fig. 2 - Current Ratings Characteristics

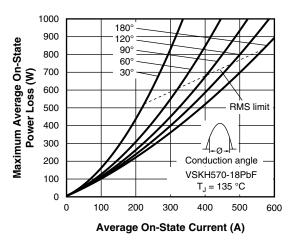


Fig. 3 - On-State Power Loss Characteristics

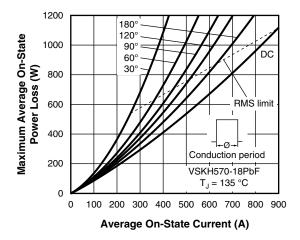


Fig. 4 - On-State Power Loss Characteristics

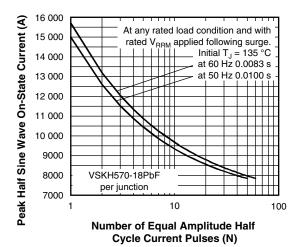


Fig. 5 - Maximum Non-Repetitive Surge Current

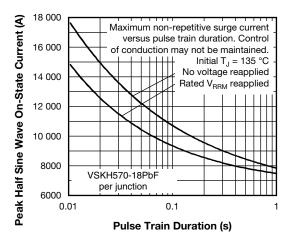
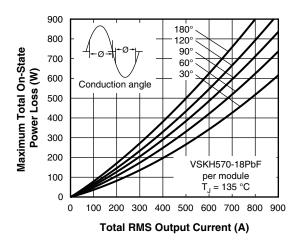


Fig. 6 - Maximum Non-Repetitive Surge Current



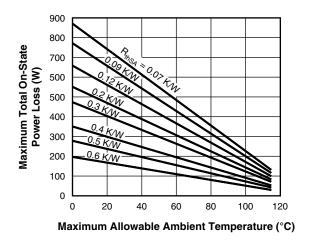


Fig. 7 - On-State Power Loss Characteristics

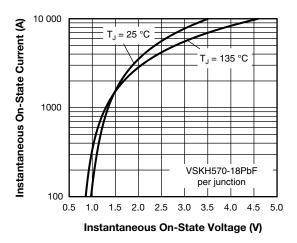


Fig. 8 - On-State Voltage Drop Characteristics

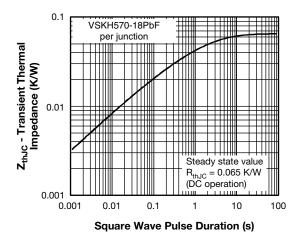


Fig. 9 - Thermal Impedance Z<sub>thJC</sub> Characteristics

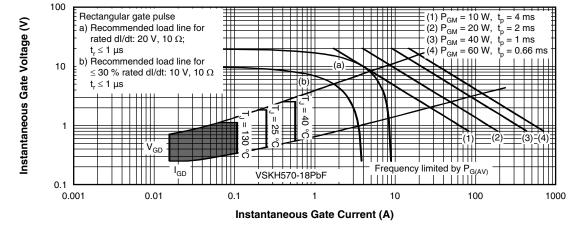
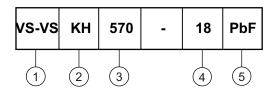


Fig. 10 - Gate Characteristics

## **ORDERING INFORMATION TABLE**





1 - Vishay Semiconductors product

Circuit configuration (see below)

Current rating

Voltage code x 100 = V<sub>RRM</sub>

5 - Lead (Pb)-free

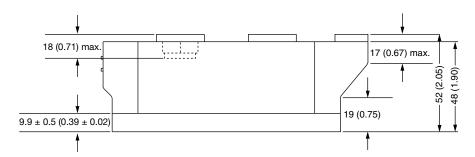
CIRCUIT DESCRIPTION	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING
SCR/diode doubler circuit	KH	VSKH  1 0 4 (K1) 0 5 (G1)

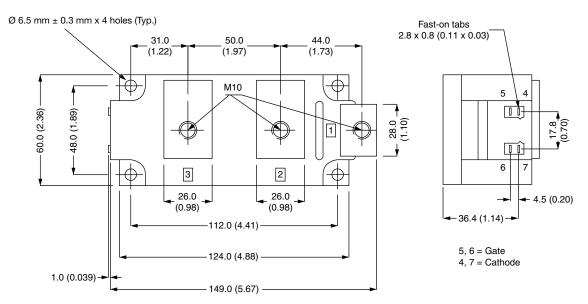
LINKS TO RELAT	ED DOCUMENTS
Dimensions	www.vishay.com/doc?95283



# **Super MAGN-A-PAK Thyristor/Diode**

## **DIMENSIONS** in millimeters (inches)







## **Legal Disclaimer Notice**

Vishay

## **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.